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Electronic-structure and Transport in Nanostructures based on Wannier Function

Nicola MARZARI

Dept. of Materials, Oxford Univ. Oxford, U.K. and Dept. Materials Science & Engineering, MIT, Cambridge U.S.A.

Building nanostructures Bloch by Bloch Nicola Marzari Department of Materials, Oxford University

Department of Materials Science and Engineering, MIT





Electronic-structure and quantum conductance



• Electronic-structure of nanostructures with thousands of atoms from maximally-localized Wannier functions

Bloch Theorem

The one-particle effective Hamiltonian \hat{H} in a periodic lattice commutes with the lattice-translation operator \hat{T}_{R} , allowing us to choose the common eigenstates according to the prescriptions of Bloch theorem:

$$[\hat{H}, \hat{T}_{\mathbf{R}}] = 0 \Rightarrow \Psi_{n\mathbf{k}}(\mathbf{r}) = u_{n\mathbf{k}}(\mathbf{r}) e^{i\mathbf{k}\cdot\mathbf{r}}$$

• *n*, *k* are the quantum numbers (band index and crystal momentum), *u* is periodi

Bloch Theorem

Crystal in real space:



Brillouin zone in reciprocal space:



Bloch Theorem

Crystal in real space:



Generalized Wannier Functions for Composite Bands

- $\{|\mathbf{R}n\rangle\}$ span the same space as $\{|\Psi_{n\mathbf{k}}\rangle\}$
- $|\mathbf{R}n\rangle = w_n(\mathbf{r}-\mathbf{R})$ (translational images)
- $\langle \mathbf{R}n | \mathbf{R}'m \rangle = \delta_{n,m} \, \delta_{\mathbf{R},\mathbf{R}'}$
- "maximally" localized



From Bloch Orbitals to Wannier Functions

$$|\mathbf{R}n\rangle = \int_{BZ} \Psi_{n\mathbf{k}}(\mathbf{r}) e^{-i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$



Gauge freedoms

• Arbitrary phase factor for every *n*k (Schrödinger)

$$|\mathbf{R}n\rangle = \int_{BZ} \left[e^{i\phi_n(\mathbf{k})} \psi_{n\mathbf{k}}(\mathbf{r}) \right] e^{-i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

From Bloch Orbitals to Wannier Functions

$$|\mathbf{R}n\rangle = \int_{BZ} \Psi_{n\mathbf{k}}(\mathbf{r}) e^{-i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$



Gauge freedoms

- Arbitrary phase factor for every *n*k (Schrödinger)
- Arbitrary unitary rotations $U_{mn}^{(\mathbf{k})}$ for every **k** (DFT)

$$|\mathbf{R}n\rangle = \int_{BZ} \sum_{m} U_{mn}^{(\mathbf{k})} \Psi_{m\mathbf{k}}(\mathbf{r}) e^{-i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

The Localization Functional (Foster-Boys)

$$\Omega = \sum_{n} \left[\langle \mathbf{0}n | r^2 | \mathbf{0}n \rangle - \langle \mathbf{0}n | \mathbf{r} | \mathbf{0}n \rangle^2 \right]$$

For a given set of Bloch orbitals, our goal is to minimize Ω
with respect all the sets of unitary transformations $U_{mn}^{(\mathbf{k})}$

$$|\mathbf{R}n\rangle = \int_{BZ} \sum_{m} U_{mn}^{(\mathbf{k})} \Psi_{m\mathbf{k}}(\mathbf{r}) e^{-i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

N. Marzari and D. Vanderbilt, Phys. Rev. B 56, 12847 (1997)

Position operator is ill defined !

$$\langle \psi_k | x | \psi_k \rangle = \int_{-\infty}^{\infty} x |u_k(x)|^2 dx$$



Blount identities

Position operator \Rightarrow Gradient

$$\langle \mathbf{0}n \, | \, \mathbf{r}^l \, | \, \mathbf{0}m \,
angle \ = \ rac{V}{(2\pi)^3} \int \langle \, u_{n\mathbf{k}} \, | \, \left(irac{\partial}{\partial \mathbf{k}}
ight)^l \, | \, u_{m\mathbf{k}} \,
angle \, d\mathbf{k}$$

We can then express positions and spreads as a function of the phase relations between neighboring Bloch orbitals

 $M_{mn}^{(\mathbf{k},\mathbf{b})} = \langle u_{m\mathbf{k}} | u_{n,\mathbf{k}+\mathbf{b}} \rangle$

Silicon, GaAs, Amorphous Silicon, Benzene

Valence bands









M. Fornari, N. Marzari, M. Peressi, and A. Baldereschi, Comp. Mater. Science 20, 337 (2001)

Disentanglement of Attached Bands

- Maximally-localized Wannier-like functions for conduction subspace
- Extract differentiable manifold with optimal smoothness



I. Souza, N. Marzari and D. Vanderbilt, Phys. Rev. B 65, 035109 (2002)

Iterative Minimization of Ω_{I}



- 1^{st} iteration: Choose trial subspace at each k (e.g. projected orbitals)
- i^{th} iteration: At each **k** pick the N highest eigenvectors of

$$\left[\sum_{\mathbf{b}} \hat{P}_{\mathbf{k}+\mathbf{b}}^{(i-1)} \right] \left| u_{n\mathbf{k}}^{(i)} \right\rangle = \lambda_{n\mathbf{k}}^{(i)} \left| u_{n\mathbf{k}}^{(i)} \right\rangle \quad \hat{P}_{\mathbf{k}+\mathbf{b}}^{(i-1)} : \text{Projector onto } \mathcal{S}^{(i-1)}(\mathbf{k}+\mathbf{b})$$

• Repeat until self-consistency (when spaces $\mathcal{S}(\mathbf{k})$ stabilize)

d Bands of Copper



The $e_g d$ WFs of panel (b)



Silicon: Bonding and Antibonding Orbitals



 $spread=10.68 bohr^2$

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Welcomel

This is the home of maximally-localised Wannier functions (MLWFs) and Wannier90, the computer program that calculates them. Wannier90 is released under the GNU General Public License.



Papers

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15 JAN 2010

Wannier90 (v1.2) is now available for download here.

Wannier90 seamlessly interfaced to Quantum-ESPRESSO, Abinit, Siesta, FLEUR ...

See here for our news archive.

Please cite

Wannier90: A Tool for Obtaining Maximally-Localised Wannier Functions A. A. Mostofi, J. R. Yates, Y.-S. Lee, I. Souza, D. Vanderbilt and N. Marzari Comput Phys. Commun. **178**, 685 (2008) [ONLINE JOURNAL]

in all publications resulting from your use of Wannier90.



Electronic Structure of Large Nanostructures

Electronic Ground State From Static or Dynamical Large-Scale Simulations Optimal Unitary Transformation of the Bloch Orbitals Real Space Maximally-Localized Wannier Functions



Minimization of the spread functional

$$\Omega = \sum_{n} [\langle r^2 \rangle_n - \langle \mathbf{r} \rangle_n^2]$$



N. Marzari and D. Vanderbilt, Phys. Rev. B 56, 12847 (1997)

Electronic Structure of Large Nanostructures



M. B. Nardelli, Phys. Rev. B 60, 7828 (1999) A. Calzolari, N. Marzari, I. Souza, M. B. Nardelli, Phys. Reb. B 69, 035108 (2004)

Band Structure of (8,0) and (5,5) SWNT



Disentanglement: Conduction Bands in (5,5) SWNT



MLWFs from the Disentangled Subspace

• Localization after disentanglement

$$w_n = \sum_{m=1}^N U_{mn} \boldsymbol{\psi}_m$$

- MLWFs from the disentangled subspace
 - s bond orbitals + p orbitals



(5,5) CNT + Nitrophenyl



Max-loc WFs ↔ "Exact" Tight-Binding

Compact mapping of Bloch states into local orbitals

$$\omega_n(\mathbf{r} - \mathbf{R}) = \frac{V}{8\pi^3} \int_{BZ} e^{-i\mathbf{k} \cdot \mathbf{R}} \psi_{n\mathbf{k}}(\mathbf{r}) d\mathbf{k}$$
$$\psi_{n\mathbf{k}}(\mathbf{r}) = \frac{1}{\sqrt{N_R}} \sum_{R} e^{i\mathbf{k} \cdot \mathbf{R}} \omega_n(\mathbf{r} - \mathbf{R})$$



$$\left\langle \psi_{i\mathbf{k}} \middle| \hat{\mathbf{H}} \middle| \psi_{j\mathbf{k}} \right\rangle = H_{ij}^{00} + e^{i\mathbf{k}\cdot\mathbf{R}} H_{ij}^{01} + e^{-i\mathbf{k}\cdot\mathbf{R}} H_{ij}^{0\overline{1}} \Rightarrow \mathsf{Diagonalize H Matrix}$$

Band Structure and Conductance of a (5,5) SWCNT



Exact Mapping onto a Tight-Binding Hamiltonian

(5,5) SWCNT



(8,0) SWCNT



Exponential Decay

Even in a metal, we have smoothly connected manifolds – no relation with the physical decay of the density matrix



Large Scale Calculations

• Parameterization



• Electronic structure of long 1-D structure with a little cost





Α

B-DNA Configuration

Dry, no backbone, 36° twist



Arash A. Mostofi (MIT), Electronic Structure Workshop, 13-15 June 2007, NSCU

First-Principles Study of Functionalizations

• Currently available covalent functionalizations



K. Balasubramanian and M. Burghard, Small, 1, 180 (2005)

Aryl / Hydrogen

Band structure does not depend on the chemical nature of the functional groups



Aryl / Hydrogen - Quantum Conductance



Y.-S. Lee, M. Buongiorno Nardelli, and N. Marzari, Phys. Rev. Lett. 95, 076804 (2005)

Electrical Transport Measurements

C. Klinke et al., Nano Lett. 6, 906 (2006)

Electrical Transport Measurements

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Suppression of Metallic Conductivity of Single-Walled Carbon Nanotubes by Cycloaddition Reactions

Mandakini Kanungo,¹ Helen Lu,² George G. Malliaras,¹ Graciela B. Blanchet²*

The high carrier mobility of films of semiconducting single-walled carbon nanotubes (SWNTs) is attractive for electronics applications, but the presence of metallic SWNTs leads to high off-currer in transistor applications. The method presented here, cycloaddition of fluorinated olefins, represents an effective approach toward converting the "as grown" commercial SWNT mats into high-mobility semiconducting tubes with high yield and without further need for carbon nanotubes eparation. Thin-film transistors, fabricated from percolating arrays of functionalized carbon nanotubes, exhibit mobilities >100 square centimeters per volt-second and on-off ratios of 100,000. This method should allow for the use of semiconducting carbon nanotubes in commerci electronic devices and provide a low-cost route to the fabrication of electronic inks.

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- Wannier 90: Arash Mostofi (Imperial College, London), Jonathan Yates (University of Oxford), Nicolas Poilvert (MIT), Matt Shelley (Imperial College),
- Transport: Young-Su Lee (MIT), Elise Li (MIT), Giovanni Cantele (University of Naples)

- Sparse Hamiltonians with chemical accuracy: Exact mapping of first-principles calculations onto tight binding Hamiltonians, using maximally-localized Wannier functions.
- Cycloadditions preserve the metallic conductance of carbon nanotubes even at high degrees of coverage
- Selected addends display fluxional tautomerism that
 - Can be directed with optical, chemical, or electrochemical means
 - Directly controls the conductance of the nanotubes